TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

# **SSM3K316T**

# Power Management Switch Applications High-Speed Switching Applications

• 1.8-V drive

Low ON-resistance: R<sub>on</sub> = 131 mΩ (max) (@V<sub>GS</sub> = 1.8 V)

 $R_{on} = 87 \text{ m}\Omega \text{ (max) (@V}_{GS} = 2.5 \text{ V)}$   $R_{on} = 65 \text{ m}\Omega \text{ (max) (@V}_{GS} = 4.5 \text{ V)}$  $R_{on} = 53 \text{ m}\Omega \text{ (max) (@V}_{GS} = 10 \text{ V)}$ 

# Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol		Rating	Unit	
Drain-source voltage		$V_{DSS}$		30	V	
Gate-source voltage		V <sub>GSS</sub>		± 12	٧	
Drain current	DC	$I_{D}$	(Note 1)	4.0	А	
	Pulse	I <sub>DP</sub>	I <sub>DP</sub> (Note 1) 8.0		_ ^	
Drain power dissipation		PD	(Note 2)	700	mW	
			t = 10s	1250		
Channel temperature		T <sub>ch</sub>		150	°C	
Storage temperature range		T <sub>stg</sub>		-55 to 150	°C	

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: The Junction temperature should not exceed 150°C during use.

Note 2: Mounted on an FR4 board. (25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm, Cu Pad: 645 mm<sup>2</sup>)

# 1. GATE 2. SOURCE 3. DRAIN TSM JEDEC JEITA TOSHIBA 2.8\*023 1.6\*023 1.6\*023 2.800799100 2.800791000 2.80079100

Weight: 10 mg (typ.)

### **Electrical Characteristics (Ta = 25°C)**

Charact	eristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Drain–source breakdown voltage	V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$		30	_		V	
Diaiii–source breakdowii voltage		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -12 \text{ V}$		18	_	_	V
Drain cutoff current	t	I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			_	1	μΑ
Gate leakage curre	ent	I <sub>GSS</sub>	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V}$			_	±1	μА
Gate threshold volt	age	V <sub>th</sub>	$V_{DS} = 3 V$ , $I_D = 1 mA$		0.4	_	1.0	V
Forward transfer a	dmittance	Y <sub>fs</sub>	$V_{DS} = 3 V$ , $I_D = 2 A$	(Note3)	3.8	7.7		S
Drain-source ON-resistance	R <sub>DS</sub> (ON)	$I_D = 3.0 \text{ A}, V_{GS} = 10 \text{V}$	(Note3)		42	53	- mΩ	
		$I_D = 2.0 \text{ A}, V_{GS} = 4.5 \text{ V}$	(Note3)		51	65		
		$I_D = 1.0 \text{ A}, V_{GS} = 2.5 \text{ V}$	(Note3)	_	64	87		
		$I_D = 0.5 \text{ A}, V_{GS} = 1.8 \text{ V}$	(Note3)		81	131		
Input capacitance		C <sub>iss</sub>				270		
Output capacitance		Coss	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$			56	_	pF
Reverse transfer capacitance		C <sub>rss</sub>				47	_	
Total Gate Charge		Qg	V <sub>DS</sub> = 15 V, I <sub>DS</sub> = 3.0 A V <sub>GS</sub> = 4 V		_	4.3	_	nC
Gate-Source Charge		Q <sub>gs</sub>				2.8	_	
Gate-Drain Charge		Q <sub>gd</sub>				1.5	_	
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD} = 10 \text{ V}, I_D = 2 \text{ A},$ $V_{GS} = 0 \text{ to } 2.5 \text{ V}, R_G = 4.7 \Omega$		_	20	_	ns
	Turn-off time	t <sub>off</sub>				31	_	
Drain-source forward voltage		$V_{DSF}$	$I_D = -4.0 \text{ A}, V_{GS} = 0 \text{ V}$	(Note3)	_	- 0.9	- 1.2	V

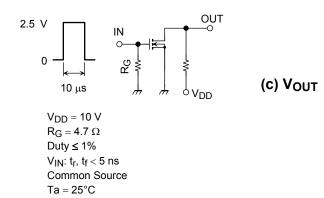
Note3: Pulse test

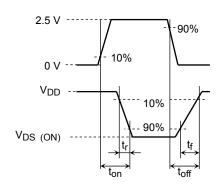
Start of commercial production 2008-04

### **Switching Time Test Circuit**

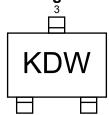
### (a) Test Circuit



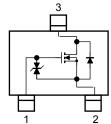




### Marking



### **Equivalent Circuit (top view)**



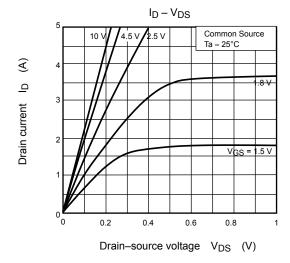
## **Usage Considerations**

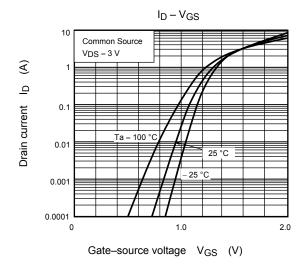
Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current (I<sub>D</sub>) to below 1 mA for the SSM3K316T). Then, for normal switching operation,  $V_{GS(on)}$  must be higher than  $V_{th}$ , and  $V_{GS(off)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(off)} < V_{th} < V_{GS(on)}$ .

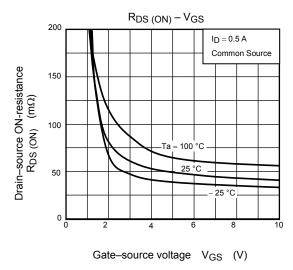
Take this into consideration when using the device.

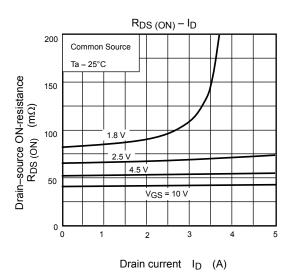
# **Handling Precaution**

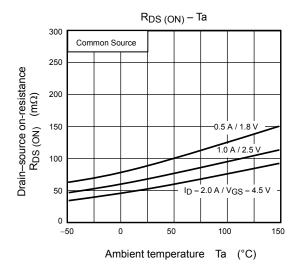
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

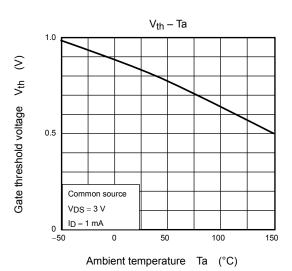


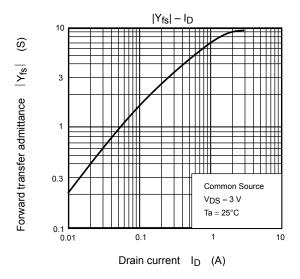


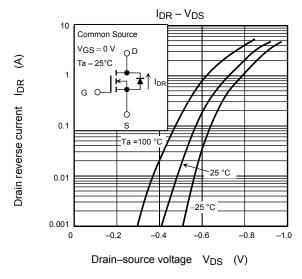


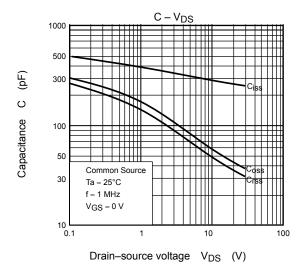


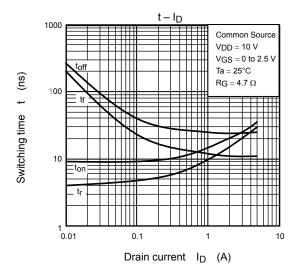


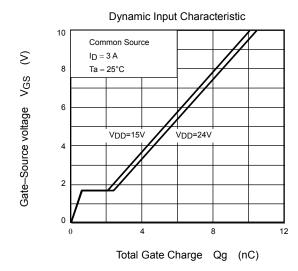




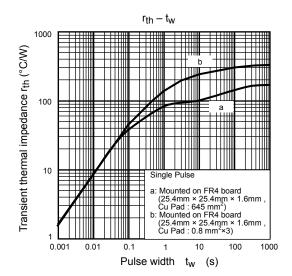


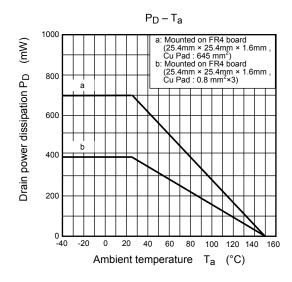






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